



ELEN 153: Digital Integrated Circuit Desb 59114

Lab 3: CMOS Inverter Layout

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Wednesday 2:15-5:00pm 2017/10/11

I. OBJECTIVE

- To develop skills for CMOS layout using Synopsys Custom Compiler.
- To create an inverter layout and verify it using DRC and LVS.
- To perform parasitic extraction and post-layout simulation.

II. LAB PROCEDURE

1. Inverter Layout

Before beginning to draw out the layout, we need to turn on DRD since it can visually indicate any design rule violation live as we draw the layout. However, the instruction in the Tutorial doesn't give the drop-down menu of DRD, instead of doing **Window→Toolbars→DRD** directly, we need to do **Tools→SDL**, press ok on the pop up, then go back to do **Window→Toolbars→DRD**. Next, open **Options->Display**, and turn on Dynamic and DX/DY so we can see X and Y measurement on the cursor as we draw.

Now we begin the layout. Note that the magnitude of every component needs to be exactly the same as told. When placing the Diffusion Contacts on PMOS, remember to enter "4" for the number of rows or there will be error if you try to add one by one.

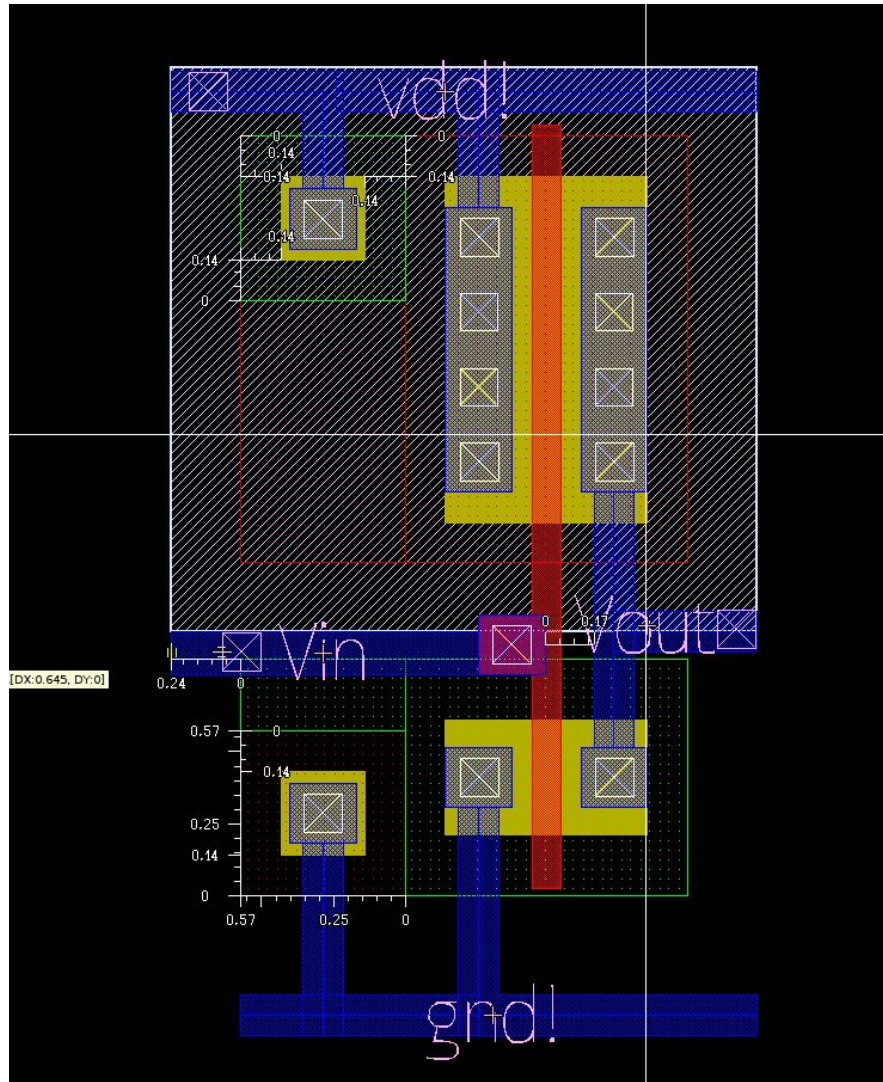


Figure 1. Final design of CMOS inverter layout

Table 1. Layout layers and their corresponding name in Synopsys tools

Layout layers	Corresponding name in Synopsys tools
N-Well	NWELL
N+ Implantation	NIMP
P+ Implantation	PIMP
Diffusion	DIFF
Poly Silicon	PO

Metal 1	M1
Metal 2	M2
Metal 1 Pin	M1PIN

2. DRC and LVS

Design Rule Check(DRC)

Select **Verification**→**DRC**→**Run**. The text view will pop-up to show the progress of the DRC. If the layout is correct in terms of rules, the screen should match Figure 3.

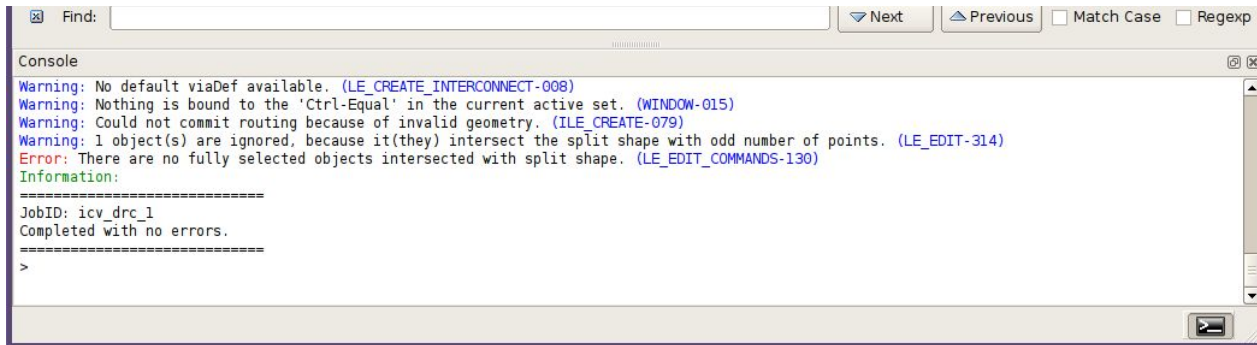


Figure 2. Console indicating no errors

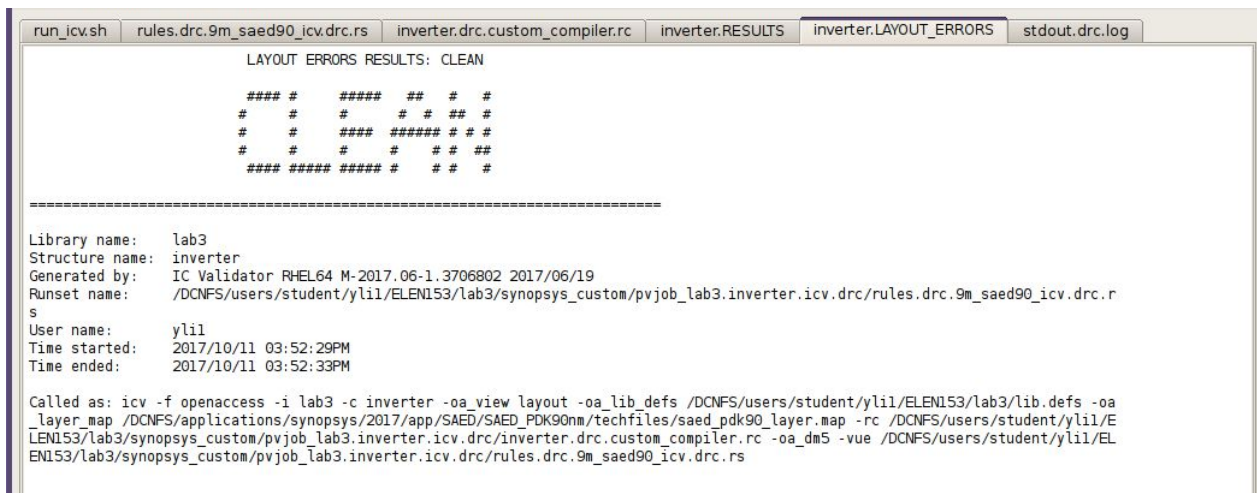


Figure 3. inverter.LAYOUT_ERRORS

Layout Vs. Schematic (LVS)

Select **Verification**→**LVS**→**Run**. At first, on the pop-up VUE window I got FAIL, as shown in Figure 4.

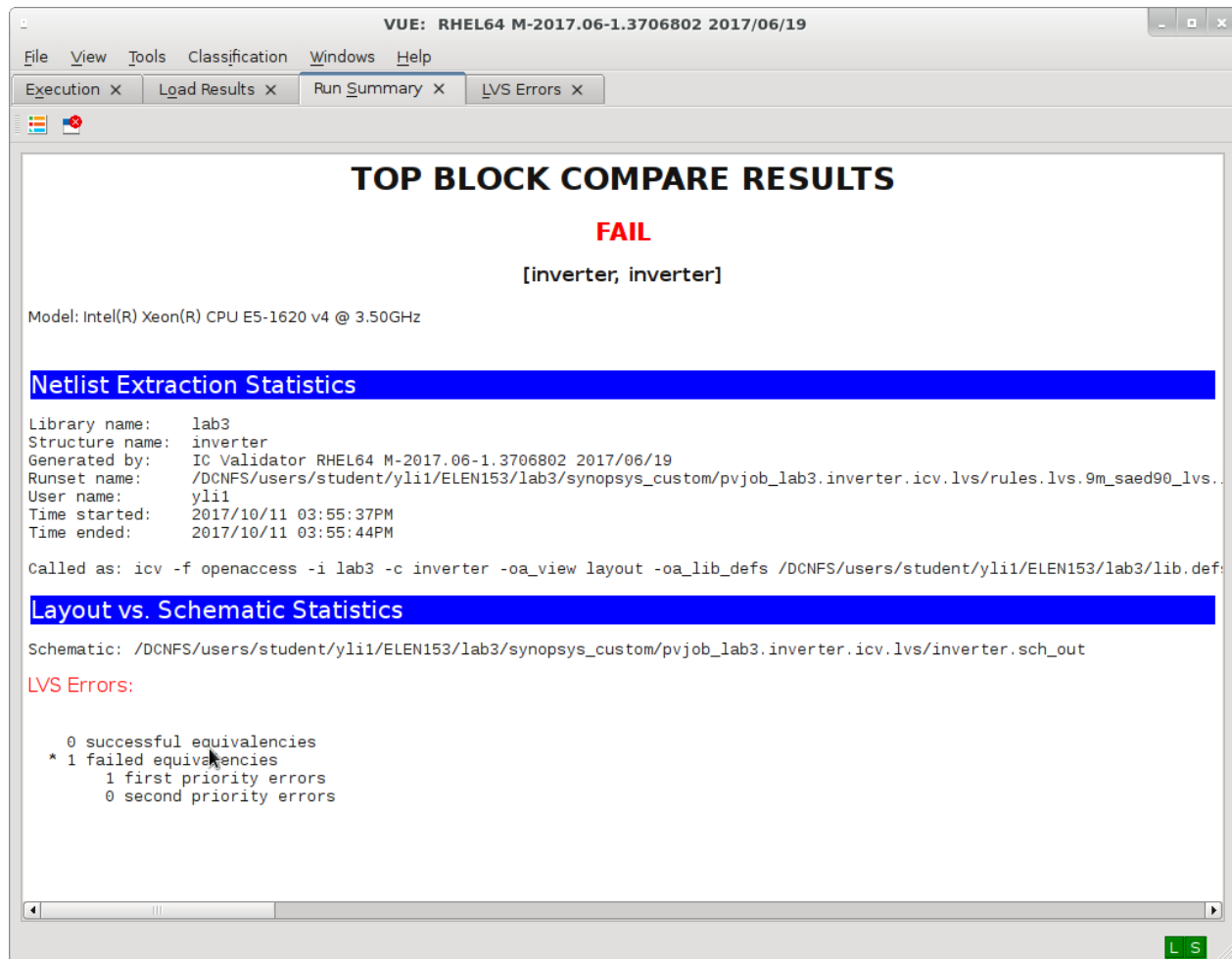


Figure 4. VUE indicating failing LVS

Then, I learn that it fails because I didn't have this layout in the same folder that holds the schematic and symbol for CMOS inverter. In order to solve this, the TA suggests and helps me build another schematic and symbol in the current file. After this modification, I got PASS.

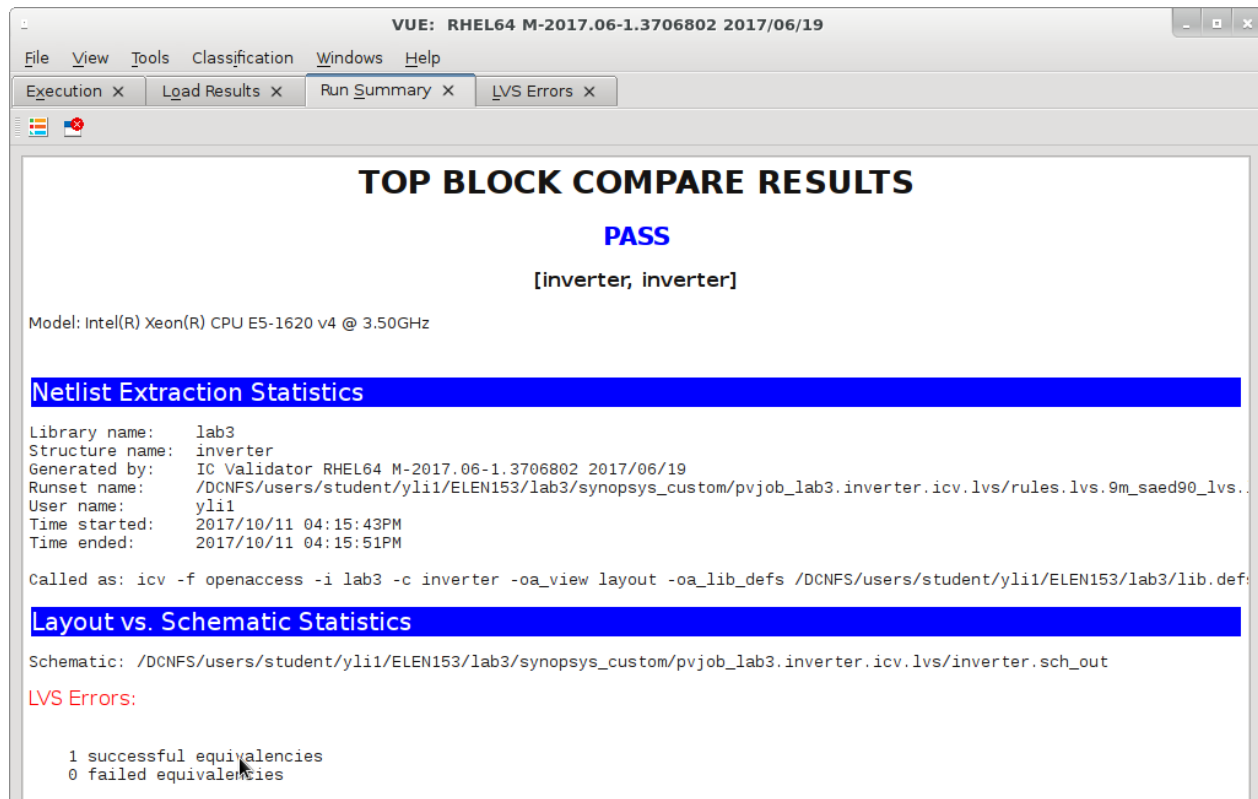


Figure 5. VUE indicating passing LVS

3. LPE and Post-Layout Simulation

Select **Verification**→**LPE**→**Setup and Run**. In the **Extraction Options** bar, include Tutorial_final_2017/synopsys_custom/pvjob_Tutorial.inverter.icv.lvs/pex_runset_report to the Runset report file.

When LPE is completed successfully, the inverter starrc view will pop-up to show the Layout parasitics on the layout as shown in Figure 6. Zoom-in so we can see there are many resistors and capacitances.

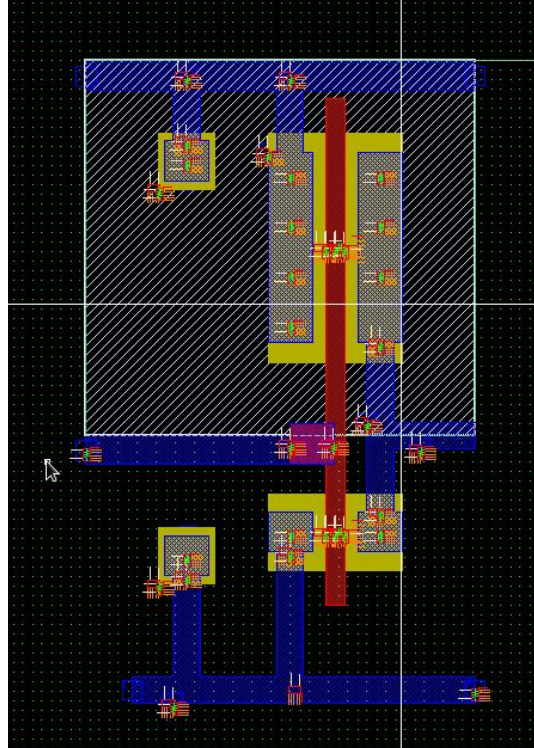


Figure 6. Inverter starrc view

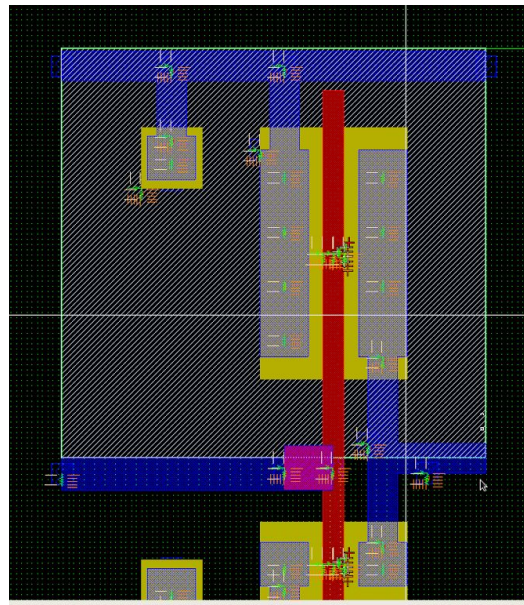


Figure 7. Detail of Figure 6

In order to do the Post-Layout Simulations, we need to create a new cellview for the testbench_inverter cell named config. Type **schematic hspice** in View Search List. Then click on the empty space under the Selected Column corresponding to the inverter, and select the **starrc** view. Then load the config state on **SAE**, perform a transient simulation, and select **append** in the Plotting Mode drop-down menu, in order to superimpose pre- and post-layout simulations.

Keep the WaveView of pre-layout simulation in order to compare with that of post-layout simulation. Change the design from config view back to schematic view to run post-layout simulation. The input and output waveforms for the pre-layout simulation will be appended to the WaveView window as shown in Figure 9.

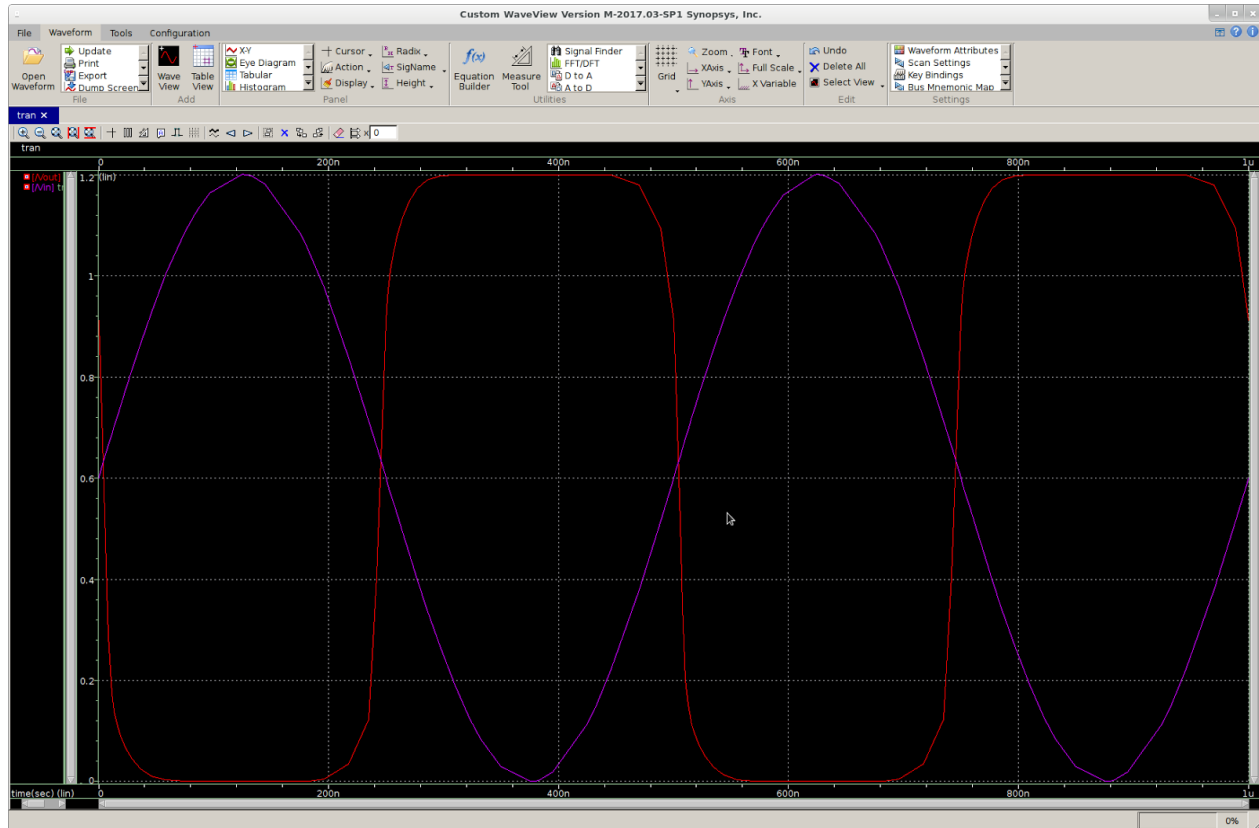


Figure 8. Pre-layout simulation waveform

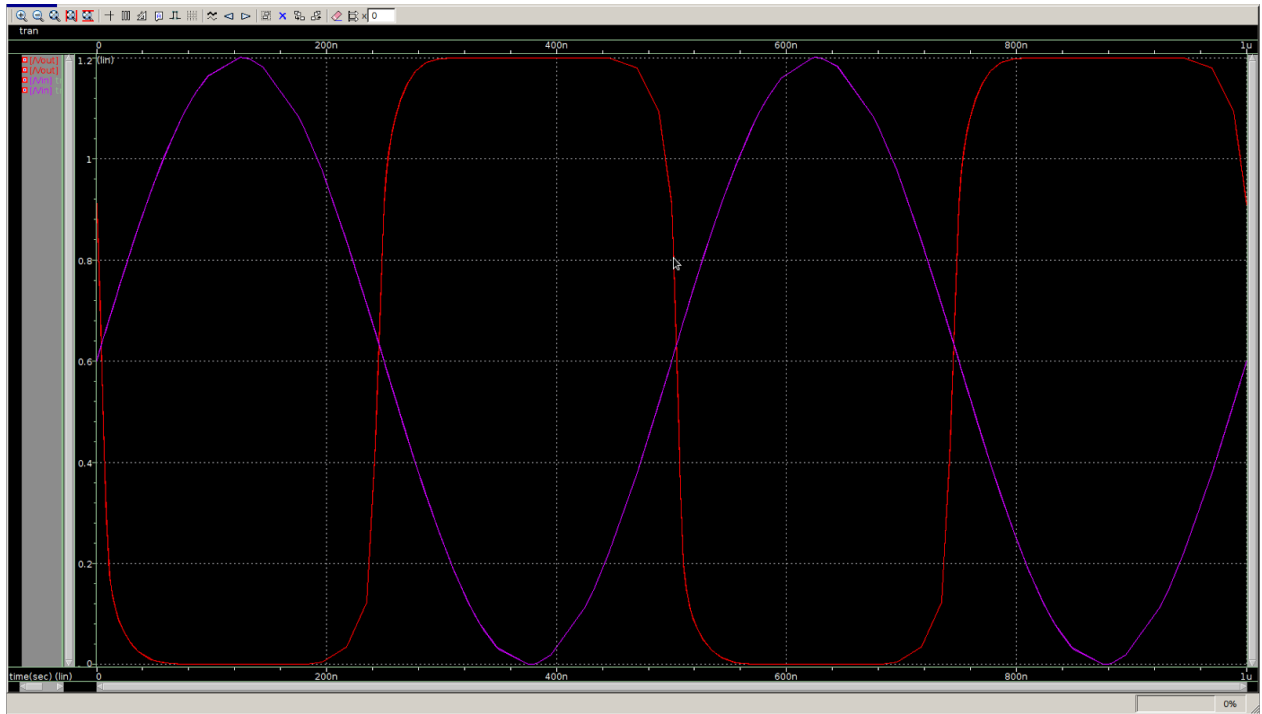


Figure 9. Post-layout simulation waveform

First, ungroup the waveforms to have 4 waveforms. Then group them so we have 2 groups: V_{out} and V_{in} , as shown in Figure 10.

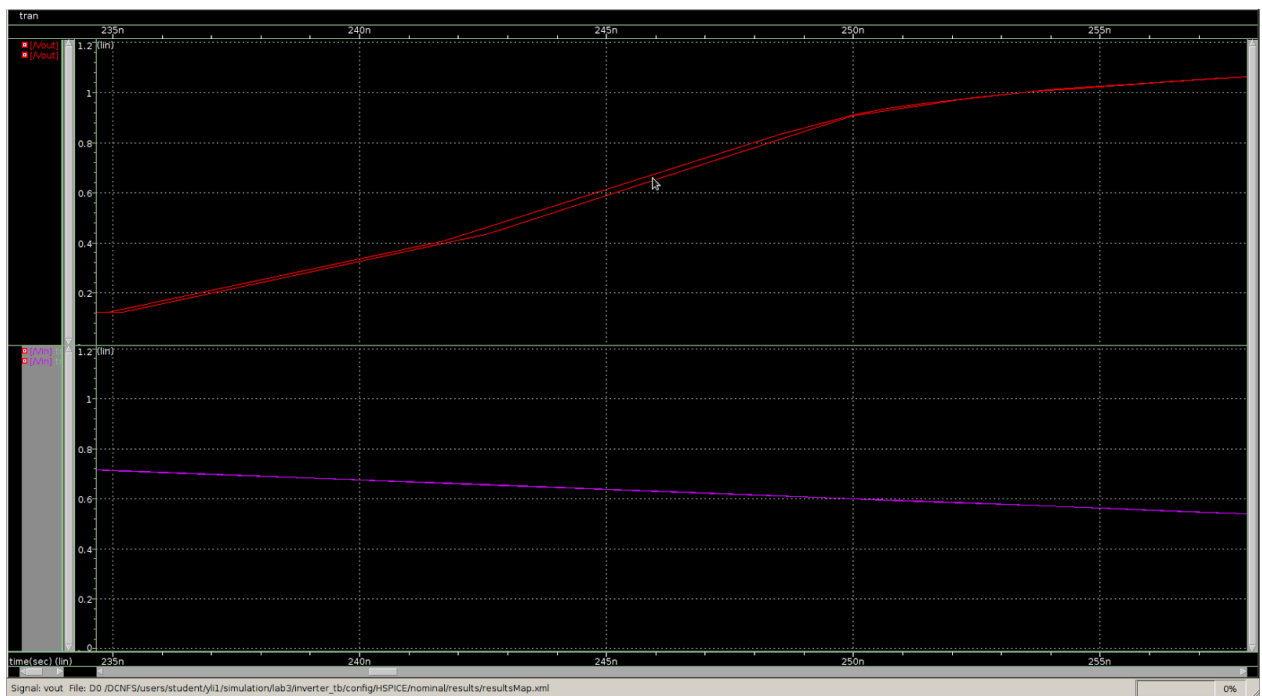


Figure 10. Waveform after ungrouping and grouping

We can see that the two waveforms of V_{out} are not identical, because of the resistors and capacitances. In our case, the number of capacitances is not huge, so the difference is small and neglectable.

III. CONCLUSION

In this lab, I learn how to create CMOS layout, verify it using DRC and LVS, and perform parasitic extraction and pre- and post-layout simulations, and notice the difference through waveform. I also learn that when creating the layout, we should be very strict about the magnitude so that we can have the layout function. During the lab, because I didn't build the layout in the same folder that holds the symbol and schematic for the CMOS inverter, I had to either rebuild the schematic and symbol in the current file, or rebuild the layout in the former folder. The TA suggested the first option, and helped me a lot with it. Also, I learnt that I forgot to add the model files again. After including the path, \$SAED90_PDK/hspice, and select TT_12, I was able to run and get the desired waveform and results.

